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Synthesis of thiol substituted oligoanilines for molecular device candidates^{*}

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Abstract—The synthesis of thioacetate derivatized oligoanilines designed for molecular electronic device purposes is described. Reversible oxidation between the non-conductive leuco base and conductive emeraldine salt forms of these compounds may produce switching effects and device behavior. The targeted compounds contain a sulfur moiety as a means to connect the molecules to metallic electrodes.

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Increasing costs and physical barriers attributed with silicon based solid-state computing technology have given way to substantial work in the field of molecular electronics. 1-3 It has been shown that single molecules can undergo reversible switching behavior in solid-state testbeds. 4 We have designed and synthesized oligoaniline-based molecules as a new class of potential switching and memory type devices. Oligoanilines offer the possibility to reversibly oxidize between different conductivity states in a controlled fashion, 5 namely between the non-conductive leuco base and the conductive emeraldine salt giving rise to a potential on-off 'memory-like' effect.

Extensive research on couplings of aryl halides with anilines by Buchwald and Hartwig^{6,7} has facilitated the synthesis of oligoanilines. We introduce a new series of oligoanilines for use as potential molecular electronic

devices by incorporating a sulfur moiety into the molecule, which allows contact between the molecule and a metal electrode. We also synthesized oligomers with methylated nitrogen atoms to ensure oxidation only to the highly conductive emeraldine salt and not to the non-conductive emeraldine base or leuco salt, provided pH is controlled. Additionally, each nitrogen atom is capable of losing one electron, therefore the structures here could offer multiple independent electronic states. The structures of the oligoaniline targets (1–5) are shown in Figure 1.

The synthesis of oligomer **1** is shown in Scheme 1. Employing Buchwald's conditions,⁶ *N*-phenyl-*p*-phenylenediamine was coupled to 2-(trimethylsilyl)ethyl-4'-bromophenyl sulfide,⁹ to afford **6**. Due to the harsh coupling conditions, the robust ethyl-trimethylsilyl protecting group was employed rather

Figure 1. Oligoaniline targets for device assembly and testing.

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Scheme 1. Synthesis of the monothiol oligoaniline dimer 1.

than the more labile thioacetate. Deprotection of the ethyltrimethylsilyl group using tetrabutylammonium fluoride⁹ and quenching with excess 1 M HCl afforded 1 as the free thiol.

The synthesis of oligoaniline 2 (Scheme 2) began by coupling p-phenylenediamine to 2-(trimethylsilyl)ethyl-4'-bromophenyl sulfide to afford the dicoupled product 7. Deprotection of 7 using tetrabutylammonium fluoride followed by quenching with acetyl chloride afforded the dithioacetate oligoaniline dimer 2. Attempts to quench the dithiolate with HCl in order to isolate the dithiol resulted in the formation of a poly-(disulfide) mixture. However, quenching with acetyl chloride affords the dithioacetate which can be deprotected in situ and assembled on gold in a manner similar to that used for the monothiol. 10 Therefore, the thioacetate moieties provide a convenient handle for isolation, particularly when the targets are α, ω -difunctionalized, since the aromatic thiols are so prone to oxidative dimerization.

Our attempts to synthesize 3 via deprotection of an ethyltrimethylsilyl group proved ineffective, therefore we used an alternative route as shown in Scheme 3. Coupling N-phenyl-p-phenylenediamine with p-dibromobenzene afforded the desired product 8. Treating 8 with methyllithium at -78°C followed by the addition

of methyl iodide at -60° C afforded intermediate 10 in excellent yield. Reacting 10 with *tert*-butyllithium followed by the addition of sulfur and quenching with acetyl chloride afforded the target device 3. We also synthesized the unfunctionalized oligoaniline dimer 9^{11} by coupling *N*-phenyl-*p*-phenylenediamine with bromobenzene, as well as the unfunctionalized *N*-methyl dimer 11^{12} by treating 9 with methyllithium and quenching with methyl iodide. 9 and 11 were needed for subsequent electrochemical characterization as models for surface-bound 3.

The N,N'-dimethyl dithioacetate dimer **4** was synthesized in a similar fashion. As shown in Scheme **4**, p-phenylenediamine was coupled to p-dibromobenzene to afford the dicoupled product **12**. Treating **12** with methyllithium followed by methyl iodide afforded the dibromo species **13**. Reacting **13** with *tert*-butyllithium at -78° C followed by the addition of sulfur and quenching with acetyl chloride gave **4**.

The synthesis of the tetramer **5** (Scheme 5) was accomplished by coupling the dibromide **13** with *N*-phenyl-*p*-phenylenediamine which afforded the monocoupled intermediate. Reacting immediately (to avoid air oxidation to the diiminoquinone) with methyllithium followed by methyl iodide, yielded the monobromo tetramer **14**. Treating **14** with *tert*-butyllithium, then sulfur and acetyl chloride afforded the target com-

Scheme 2. Synthesis of the dithioacetate oligoaniline 2.

Scheme 3. Synthesis of *N*-methyl oligoaniline dimers.

Scheme 4. Synthesis of the dithioacetate oligoaniline dimer 4.

Scheme 5. Synthesis of the monothioacetate oligoaniline tetramer 5 and unfunctionalized tetramer 15.

pound **5**, albeit in low yield. For electrochemical characterization, we also synthesized the unfunctionalized *N*-methyl tetramer **15** by coupling **10** with *N*-phenyl-*p*-phenylenediamine, followed by treatment with methyllithium and methyl iodide.

We plan to assess the compounds synthesized¹⁴ in this work in several testbeds, including the nanopore and planar devices,¹⁵ as well as the cross wire test structure.¹⁶ These results will be reported separately.

Acknowledgements

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References

- 1. Service, R. F. Science 2001, 294, 2442-2443.
- 2. Tour, J. M. Molecular Electronics: Commercial Insights, Chemistry, Devices, Architecture and Programming; World Scientific: New Jersey, 2003.
- Bumm, L. A.; Arnold, J. J.; Cygan, M. T.; Dunbar, T. D.; Burgin, T. P.; Jones, L., II; Allara, D. L.; Tour, J. M.; Weiss, P. S. Science 1996, 271, 1705–1707.
- Chen, J. R.; Reed, M. A.; Rawlett, A. M.; Tour, J. M. Science 1999, 286, 1550–1552.

- Paul, E. W.; Ricco, A. J.; Wrighton, M. S. J. Phys. Chem. 1985, 89, 1441–1447.
- Wolfe, J. P.; Buchwald, S. L. J. Org. Chem. 2000, 65, 1144–1157.
- 7. Louie, J.; Driver, M. S.; Hamann, B. C.; Hartwig, J. F. *J. Org. Chem.* **1997**, *62*, 1268–1273.
- 8. Manohar, S. K.; MacDairmid, A. G. Synth. Met. 1989, 29, E349–E356.
- Yu, C. J.; Chong, Y.; Kayyem, J. F.; Gozin, M. J. Org. Chem. 1999, 64, 2070–2079.
- Cai, L.; Yao, Y.; Yang, J.; Price, D. W., Jr.; Tour, J. M. Chem. Mater. 2002, 14, 2905–2909.
- Schuster, D. I.; Rosenthal, J.; MacMahon, S.; Jarowski,
 P. D.; Alabi, C. A.; Guldi, D. M. Chem. Commun. 2002,
 21, 2538–2539.
- Weller, H.; Grellmann, K. H. J. Am. Chem. Soc. 1983, 105, 6268–6273.
- Sadighi, J. P.; Singer, R. A.; Buchwald, S. L. J. Am. Chem. Soc. 1998, 120, 4960–4976.
- 14. Selected characterization data. 1: Mp: 151–160°C. IR (KBr) 3397.99, 3019.09, 2399.90, 1596.86, 1514.52, 1424.96, 1215.54 cm⁻¹. 1 H NMR (400 MHz, CDCl₃) δ 7.28 (m, 4H), 7.05 (m, 6H), 6.90 (m, 3H), 5.63 (s, 1H), 5.59 (s, 1H), 3.41 (s, 1H). 13 C NMR (100 MHz, CDCl₃) δ 144.7, 143.9, 138.0, 137.0, 133.0, 129.8, 121.7, 121.1, 120.6, 118.7, 117.3, 117.0. HRMS calcd for C₁₈H₁₆N₂S: 292.1034. Found: 292.1033. **2**: Mp: 198–200°C. IR (KBr) 3428.85, 3019.22, 2400.00, 1699.20, 1595.12, 1514.21, 1424.26, 1215.46 cm⁻¹. 1 H NMR (400 MHz, (CD₃)₂CO) δ 7.59 (s, 2H), 7.22 (d, J=8.3 Hz, 4H), 7.20 (s, 4H), 7.07 (d, J=8.3 Hz, 4H), 2.35 (s, 6H). 13 C NMR (100 MHz,

 $(CD_3)_2CO$) δ 195.4, 147.5, 137.7, 136.8, 122.2, 116.9, 116.2, 29.8. HRMS calcd for $C_{22}H_{20}N_2O_2S_2$: 408.0966. Found: 408.0961. 3: Mp: 104-106°C. IR (KBr) 3018.03, 2943.21, 2882.87, 2815.66, 2400.24, 1696.27, 1593.38, 1496.63, 1338.79, 1255.20, 1215.80, 1190.46, 1131.55 cm⁻¹. ¹H NMR (400 MHz, (CD₃)₂CO) δ 7.29 (m, 2H), 7.19 (d, J=9.1 Hz, 2H), 7.14 (d, J=9.1 Hz, 2H), 7.06 (m,4H), 6.95 (t, J=7.1 Hz, 1H), 6.81 (d, J=9.1 Hz, 2H), 3.33 (s, 3H), 3.31 (s, 3H), 2.33 (s, 3H). ¹³C NMR (100 MHz, $(CD_3)_2CO$) δ 196.6, 150.8, 149.4, 146.5, 141.8, 135.9, 129.7, 127.0, 121.9, 121.8, 120.8, 115.8, 115.1, 40.8, 40.7, 30.3. HRMS calcd for C₂₂H₂₂N₂OS: 362.1454. Found: 3623.1453. 4: Mp: 168-170°C. IR (KBr) 3018.40, 2884.21, 2816.94, 2400.23, 1887.47, 1693.94, 1591.40, 1556.23, 1495.02, 1453.60, 1423.00, 1337.34, 1254.98, 1216.42, 1190.52, 1120.45, 1074.64 cm⁻¹. ¹H NMR (400 MHz, $(CD_3)_2CO$) δ 7.23 (m, 8H), 6.92 (d, J=8.9 Hz, 4H), 3.36 (s, 6H), 2.35 (s, 6H). ¹³C NMR (100 MHz, $(CD_3)_2CO)$ δ 194.7, 150.6, 144.8, 136.0, 126.1, 116.8, 116.7, 40.1, 29.3. HRMS calcd for C₂₄H₂₄N₂O₂S₂: 436.1279. Found: 436.1275. 5: Mp: 148-152°C. IR (KBr) 3018.89, 2399.90, 1693.59, 1593.26, 1498.93, 1423.92, 1333.27, 1215.92, 1133.39 cm⁻¹. ¹H NMR (400 MHz, $(CD_3)_2CO$ δ 7.19 (m, 4H), 7.05 (m, 10H), 6.93 (d, J=8.7

- Hz, 2H), 6.89 (m, 2H), 6.8 (t, J=6.9 Hz, 1H), 6.75 (d, J=8.7 Hz, 2H), 3.30 (m, 6H), 3.28 (s, 3H), 3.27 (s, 3H), 2.33 (s, 3H). 13 C NMR (100 MHz, THF- d_8) δ 194.6, 151.7, 150.7, 148.3, 146.1, 145.8, 144.0, 143.5, 140.7, 136.2, 129.6, 127.7, 125.0, 124.8, 122.3, 121.8, 120.0, 119.1, 118.3, 115.9, 115.4, 40.8, 40.6, 40.6, 29.5. HRMS calcd for C₃₆H₃₆N₄OS: 572.2610. Found: 572.2600. **15** Mp: 208–210°C. IR (KBr) 3019.23, 2400.21, 1596.94, 1503.67, 1332.57, 1216.19, 1133.53 cm⁻¹. 11 H NMR (500 MHz, THF- d_8) δ 7.12 (t, J=9.9 Hz, 4H), 6.96 (m, 8H), 6.89 (d, J=9.9 Hz, 4H), 6.81 (d, J=9.9 Hz, 4H), 6.72 (t, J=9.9 Hz, 2H), 3.25 (s, 6H), 3.23 (s, 6H). 13 C NMR (100 MHz, THF- d_8) δ 148.3, 143.9, 142.3, 140.7, 127.1, 122.9, 120.5, 118.5, 117.1, 115.2, 38.4, 38.1. HRMS calcd for C₃₄H₃₄N₄: 498.2783. Found: 498.2791.
- Price, D. W., Jr.; Dirk, S. M.; Rawlett, A. M.; Chen, J.; Wang, W.; Reed, M. A.; Zacarias, A. G.; Tour J. M. Mat. Res. Soc. Symp. Proc. 2001, 660, JJ9.4.1/D7.4.1-JJ9.4.9/D7.4.9.
- Kushmerick, J. G.; Holt, D. B.; Pollack, S. K.; Ratner, M. A.; Yang, J. C.; Schull, T. L.; Naciri, J.; Moore, M. H.; Shashidhar, R. J. Am. Chem. Soc. 2002, 124, 10654– 10655.